

Voltage Detector (Reset) IC Series for Automotive Application

Free Time Delay Setting CMOS Voltage Detector (Reset) IC

BD521VNVX-2C

General Description

ROHM's Free Time Delay Setting CMOS Voltage Detector ICs are highly accurate, with ultra-low current consumption feature that uses CMOS process. Delay time setting can be control by an external capacitor. The lineup includes N-channel open drain output with detection voltage of 0.965 V.

The time delay has ± 50 % accuracy in the overall operating temperature range of -40 °C to 125 °C.

Features

- Nano Energy[™]
- AEC-Q100 Qualified^(Note 1)
- Delay Time Setting Controlled by External Capacitor
- Nch Open Drain Output Type

Typical Application Circuit

Miniature Surface-mount Package (Note 1) Grade 1

Key Specifications

Detection Voltage:

- 0.965 V (Typ)
- Ultra-Low Current Consumption: 270 nA (Typ)
- Time Delay Accuracy: ±50 % (-40 °C to +125 °C,
 - CT pin capacitor ≥ 1 nF)

Special Characteristics

- Detection Voltage Accuracy:
 - ±3.0 %±12 mV (V_{DET} = 0.965 V)

Package SSON004R1010: W (Typ) x D (Typ) x H (Max) 1.0 mm x 1.0 mm x 0.6 mm



Application

All automotive devices that requires voltage detection

BD521VNVX-2C

Pin Configuration



SSON004R1010

Pin Description

SSON004R1010					
PIN No.	PIN NAME	Function			
1	GND	GND			
2	VDD	Power supply voltage			
3	VOUT	Output pin			
4	ОТ	Capacitor connection pin for			
4	CI	output delay time setting			
-	EXP-PAD	Leave it open			

Nano Energy™ is a trademark or a registered trademark of ROHM Co., Ltd.

OProduct structure : Silicon integrated circuit OThis product has no designed protection against radioactive rays.

Block Diagram



Ordering Information 2 Х 2 С В D 5 1 V Ν V Т L Detection Voltage 1V: 0.965 V NVX: SSON004R1010 Packing and Forming Product Rank Specification C: for Automotive TL: Embossed tape and reel **Marking Diagram**



Absolute Maximum Ratings (Ta = 25 °C)

Para	imeter	Symbol	Limit	Unit
Power Supply Voltage		V _{DD} - GND	-0.3 to +7	V
Output Voltage Nch Open Drain Output		Vout	GND - 0.3 to +7	V
Output Current		lo	70	mA
Maximum Junction Temp	perature	Tjmax	+150	°C
Storage Temperature Ra	nge	Tstg	-55 to +150	°C

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

Thermal Resistance^(Note 1)

Deremeter	Symbol	Thermal Res	Linit	
Parameter	Symbol	1s ^(Note 3)	2s2p ^(Note 4)	Unit
SSON004R1010				
Junction to Ambient	θја	450.2	97.1	°C/W
Junction to Top Characterization Parameter ^(Note 2)	Ψ_{JT}	99	22	°C/W

(Note 1) Based on JESD51-2A(Still-Air). (Note 2) The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.

Note	3) Using	a PCB	board	based	on	JESD51-3.	
	411111		the second second	the second second			

(Note 4) Using a PCB board based of	n JESD51-5, 7.				
Layer Number of Measurement Board	Material	Board Size			
Single	FR-4	114.3 mm x 76.2 mm x	x 1.57 mmt		
Тор					
Copper Pattern	Thickness				
Footprints and Traces	70 µm				
Layer Number of	Matarial	Doord Size		Thermal Vi	a ^(Note 5)
Measurement Board	Material	Board Size		Pitch	Diameter
4 Layers	FR-4	114.3 mm x 76.2 mm	x 1.6 mmt	1.20 mm	Ф0.30 mm
Тор		2 Internal Laye	ers	Bottor	n
Connor Dottorn	Thickness	Connor Dattorn	Thickness	Conner Pattern	Thickness
Copper Pattern	Thickness	Copper Falleni	THICKIESS	Copper r attern	THICKICSS

(Note 5) This thermal via connect with the copper pattern of layers 1,2, and 4. The placement and dimensions obey a land pattern.

Function Explanation

1. Nano Energy™

Nano Energy[™] is a combination of technologies which realizes ultra low quiescent current operation.

Recommended Operating Conditions

Parameter	Symbol	Min	Тур	Max	Unit
Operating Temperature	Topr	-40	+25	+125	°C

Electrical Characteristics (Unless otherwise specified Ta = -40 °C to +125 °C, VDD = 0.8 V to 6.0 V)

Deremeter	Symbol	Condition	Limit			Lloit
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Detection Voltage	V _{DET}	$\label{eq:VDET} \begin{split} V_{\text{DET}} &= 0.965 \text{ V}, \text{ V}_{\text{DD}} = \text{H} \rightarrow \text{L}, \\ \text{RL} &= 100 \text{ k}\Omega^{(\textit{Note 2})} \end{split}$	V _{DET} (T) × 0.97 - 0.012	V _{DET} (T) (Note 1)	V _{DET} (T) × 1.03 + 0.012	V
Hysteresis Voltage	$\Delta \text{V}_{\text{DET}}$	$V_{\text{DD}} = L \rightarrow H \rightarrow L, R_{\text{L}} = 100 \; \text{k}\Omega$	V _{DET} × 0.03	V _{DET} × 0.05	V _{DET} × 0.07	V
Circuit Current when ON		$V_{DD} = V_{DET} - 0.2 V$	-	0.23	1.50	μA
Circuit Current when OFF	I _{DD2}	$V_{DD} = V_{DET} + 0.5 V$	-	0.27	1.60	μA
Minimum Operating Voltage	VOPL	$V_{OL} \le 0.4$ V, $R_L = 100$ k $\Omega^{(Note 2)}$	0.80	-	-	V
"Low" Output Voltage (Nch)	V _{OL}	V _{DD} = 0.8 V, I _{SINK} = 0.17 mA, V _{DET} = 0.965 V	-	-	0.4	V
Output Leak Current	lleak	$V_{DD} = V_{DS} = 6 V$	-	-	1.0	μA
Delay Time (L \rightarrow H)	tрьн	$ V_{\text{OUT}} = GND \rightarrow 50 \text{ \%, } C_{\text{CT}} = 0.01 \mu\text{F} $ (Note 3) (Note 4)	27.7	55.5	97.1	ms

(Note 1) V_{DET}(T): Standard Detection Voltage (0.965 V)

(Note 2) R_L : Pull-up resistor connected between V_{OUT} and power supply

(Note 3) t_{PLH}: V_{DD} = (V_{DET}(T) - 0.1 V) \rightarrow (V_{DET}(T) + 0.5 V)

(Note 4) CT delay capacitor range: open to 4.7 µF

Typical Performance Curves



Figure 3. Circuit Current vs Power Supply Voltage

Figure 4. Circuit Current vs Temperature



Figure 5. Detection Voltage vs Power Supply Voltage

Figure 6. Detection Voltage vs Temperature

Typical Performance Curves - continued



Figure 9. Minimum Operating Voltage vs Temperature (VOUT Pull-up to 5 V, R_L = 100 k Ω)

Figure 10. Minimum Operating Voltage vs Temperature (VOUT Pull-up to V_{DD}, R_L = 100 k\Omega)

Typical Performance Curves - continued



Figure 13. Delay Time (L \rightarrow H) vs CT Pin Capacitance



Typical Performance Curves - continued





Figure 15. "Low" Output Current vs Drain-Source Voltage (V_{DD} = 0.8 V)

Figure 16. "Low" Output Current vs Power Supply Voltage (V_{DS} = 0.5 V)

Application Information

Operation Description

For the open drain type (Figure 17), the detection and release voltage are used as threshold voltages. When the voltage applied to the V_{DD} reaches the applicable threshold voltage, the V_{OUT} level switches from either "H" \rightarrow "L" or from "L" \rightarrow "H". BD521VNVX-2C have delay time function, which set t_{PLH} (output "L" \rightarrow "H") using an external capacitor connected in CT pin (C_{CT}).

Because the BD521VNVX-2C use an open drain output type, it is necessary to connect a pull up resistor to V_{DD} or another power supply. [In this case, the output (V_{OUT}) "H" voltage becomes V_{DD} or the voltage of the other power supply].



Figure 17. (BD521VNVX-2C internal block diagram)

Setting of Detector Delay Time

Delay time L \rightarrow H (t_{PLH}) is the time when V_{OUT} rises to 1/2 of V_{DD} after V_{DD} rises up and beyond the release voltage (V_{DET} + Δ V_{DET}).

Delay time $L \rightarrow H$ (t_{PLH}) is determined by CT capacitor and can be calculated from the following formula. When CT capacitor $\geq 1nF$, t_{CTO} has less effect and t_{PLH} computation is shown on Example No.2. The result has ±50 % tolerance within the operating temperature range of -40 °C to +125 °C.

Formula: (Ta = 25 °C)

$$t_{PLH} = C_{CT} \times Delay Coefficient + t_{CTO}$$
 [s]

where:

 C_{CT} is the CT pin external capacitor $Delay \ Coefficient$ is equal to 5.55 x 10⁶ t_{CTO} is the delay time when CT = open^(Note 1)

Tomorofuno	Delay Time (tсто)				
remperature	Min	Тур	Max		
Ta = -40 °C to +125 °C	15 µs	50 µs	150 µs		

(Note 1) t_{CTO} is design guarantee only

Example No.1: CT capacitor = 100 pF

 $t_{PLH_min} = (100 \times 10^{-12} \times 5.55 \times 10^{6}) \times 0.5 + 15 \times 10^{-6} = 292 \,\mu s$ $t_{PLH_typ} = (100 \times 10^{-12} \times 5.55 \times 10^{6}) \times 1.0 + 50 \times 10^{-6} = 605 \,\mu s$ $t_{PLH_max} = (100 \times 10^{-12} \times 5.55 \times 10^{6}) \times 1.5 + 150 \times 10^{-6} = 983 \,\mu s$

Example No.2: CT capacitor = 1 nF

 $t_{PLH_typ} = 1 \times 10^{-9} \times 5.55 \times 10^6 = 5.55 \, ms$

Application Information - continued

Timing Waveform

The following shows the relationship between the input voltage V_{DD} and the output voltage V_{OUT} when the power supply voltage V_{DD} is sweep up and sweep down.



Figure 18. BD521VNVX-2C Set-up



Operating Conditions Explanation

- 1 When the power supply turns on, the Output Voltage (V_{OUT}) becomes unstable until V_{DD} exceeds the Minimum Operating Voltage (V_{OPL}).
- 2 V_{OUT} changes to "L". However, this change depends on the V_{OUT} rise time when the power supply starts up, so thorough confirmation is required.
- 3 When V_{DD} exceeds the release voltage (V_{DET} + ΔV_{DET}), delay time (t_{PLH}) set by the capacitor at CT pin (C_{CT}) happens, then V_{OUT} switches from "L" to "H".
- 4 VOUT remains "H".
- 5 When V_{DD} drops below Detection Voltage (V_{DET}), delay time (t_{PHL}) happens, then V_{OUT} switches from "H" to "L".

The potential difference between the detection voltage and the release voltage is known as the Hysteresis Voltage width (ΔV_{DET}). The system is designed such that the output will not toggle with power supply fluctuations within this hysteresis width, preventing malfunctions due to noise.

Application Information – continued

Bypass Capacitor for Noise Rejection

To help reject noise, put more than 0.1 µF capacitor between the VDD and GND pins and connect it closer to the pin as possible. Be careful when using extremely big capacitor as transient response will be affected.

External Parameters

The recommended value of CT capacitor is from open to 4.7 μ F and pull-up resistance value is 50 k Ω to 1 M Ω . There are many factors (board layout, etc.) that can affect characteristics. Operating beyond the recommended values does not guarantee correct operation. Verify and confirm using practical applications.

In addition, this IC has extremely high impedance pins. Small leak current due to the uncleanness of PCB surface might cause unexpected operations. Application values in these conditions should be selected carefully. For example, if a 10 M Ω leakage is assumed between the VOUT and GND pins, consider to set the value of pull up resistor lower than 1/10 of the impedance of assumed leakage route.

Behavior when below the Operating Voltage Limit

When V_{DD} falls below the minimum operating voltage, output will be open. When output is connected to pull-up voltage, output will be equivalent to pull-up voltage.

CT Pin Discharge

Due to the capabilities of the CT pin discharge transistor, the CT pin may not completely discharge when a short input pulse is applied, and in this case the delay time may not be controlled. Verify the actual operation.

Application Circuits

(1) Examples of common application circuits



Figure 20. Open Drain Output Type

Application example of BD521VNVX-2C(Open drain output type) is shown below.

If the power supply of the microcontroller differs from the power supply of the detection (V_{DD1}), use the load resistance R_L connected to V_{DD2} in the output of open drain output type (BD521VNVX-2C) as shown in Figure 20.

When connecting a capacitor C_L for noise elimination and for output time delay setting to the VOUT pin (reset signal input pin of micro-controller), the waveform is dull during rising and falling of the output so use after confirmation that there is no problem.

Application Circuits – continued

(2) The following is an example of an OR connection between two types of detection voltage resets the microcontroller.



There are multiple power supply in the system, and in case monitoring for each independent power supply V_{DD1} and V_{DD2} and reset of micro-controller is required, an application where output "H" voltage is aligned to the microcontroller power supply V_{DD3} is possible by connecting OR application and pull-up at random voltage (V_{DD3}) such as shown in Figure 21.

(3) Examples of the power supply with resistor dividers

In applications wherein the power supply voltage of an IC comes from a resistor divider circuit, an inrush current will flow into the circuit when the output level switches from "Low" to "High" or vice versa. Inrush current is a sudden surge of current that flows from the power supply (V_{DD}) to ground (GND) as the output logic changes its state. This current flow may cause malfunction in the systems operation such as output oscillations, etc.



Figure 22. Resistor Divider Connection Application

Figure 23. Current Consumption vs V_{DD} Voltage

A voltage drop [Inrush current (I₁)] x [input resistor (R_A)] is caused by the inrush current, and causes the input voltage to drop when the output switches from "L" \rightarrow "H". When the input voltage drops and falls below the detection voltage, the output will switch from "H" \rightarrow "L". At this time, the inrush current stops flowing through output "L", and the voltage drop disappears. As a result, the output switches from "L" \rightarrow "H", which again causes the inrush current to flow and the voltage to drop. This operation repeats and leads to oscillation.

In case resistor divider is not use and only use RA, same response will happen.

(Note 1) The circuit connection mentioned above does not guarantee successful operation.

Perform thorough evaluation using the actual application and set countermeasures.

Application Circuits - continued







Depending on the application set-up, there are times that V_{DD} voltage is always below the Release Voltage ($V_{DET} + \Delta V_{DET}$) because of the effect of inrush current as shown in Figure 26.



Figure 26. V_{DD} Drop Caused by Inrush Current

Considerations on Input and Output Capacitor

It is suggested to use input and output capacitors which is positioned as near as possible to the pins. The capacitor between the input pin and GND is effective when the power supply impedance increases or when the wiring is long. A large capacitor at the output improves stability and output load characteristics. Before implementation, check the state of mounting. In addition, the ceramic capacitor deviates in general and has temperature characteristics and AC bias characteristics. Furthermore, depending on the usage, the capacitance value decreases over time. It is recommended that ceramic capacitor to use is decided after gathering detailed data information by consulting brand manufacturers.



Figure 27. Ceramic Capacitance Change - DC Bias Properties (Characteristic example)

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

8. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

9. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

10. Regarding the Input Pin of the IC

In the construction of this IC, P-N junctions are inevitably formed creating parasitic diodes or transistors. The operation of these parasitic elements can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions which cause these parasitic elements to operate, such as applying a voltage to an input pin lower than the ground voltage should be avoided. Furthermore, do not apply a voltage to the input pins when no power supply voltage is applied to the IC. Even if the power supply voltage is applied, make sure that the input pins have voltages within the values specified in the electrical characteristics of this IC.

11. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.



Revision History

Date	Revision	Changes
25.Apr.2022	001	New Release

Notice

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(Note1) Medical Equipment Classification of the Specific Application
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JAPAN	USA	EU	CHINA
CLASSⅢ		CLASS II b	
CLASSⅣ	CLASSI	CLASSⅢ	CLASSI

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 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
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- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
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For details, please refer to ROHM Mounting specification

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 - [c] the Products are exposed to direct sunshine or condensation
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